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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/002,862	11/15/2001	John Davis Holder	MEMC 01-0650 (3003)	4783
321	7590	07/14/2006	EXAMINER	
SENNIGER POWERS ONE METROPOLITAN SQUARE 16TH FLOOR ST LOUIS, MO 63102			SONG, MATTHEW J	
			ART UNIT	PAPER NUMBER
			1722	

DATE MAILED: 07/14/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No. 10/002,862	Applicant(s) HOLDER, JOHN DAVIS	
	Examiner Matthew J. Song	Art Unit 1722	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 03 May 2006.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-107 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-107 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 1-107 are rejected under 35 U.S.C. 103(a) as being unpatentable over Holder et al (US 5,588,993) in view of Kamio et al (US 5,087,429).

In a method of preparing a molten silicon melt, note entire reference, Holder teaches polycrystalline silicon 10 is loaded into a crucible 20 and chunk poly crystalline silicon is used because using chunks avoids the formation of void defects (col 3, ln 35 to col 4, ln 2). Holder also teaches polycrystalline silicon 10 is melted until a partially melted charge forms in a crucible (col 4, ln 30-65). After forming the partially melted charge in the crucible, granular polycrystalline silicon 40 is fed onto the exposed unmelted polycrystalline silicon (col 5, ln 1-60). Holder also teaches feeding the polycrystalline silicon 40 on the unmelted silicon 11 allows the silicon to dehydrogenate, which is desirable (col 5, ln 10-30). It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Nagai with Holder's method of feeding polycrystalline silicon onto the exposed unmelted polycrystalline to allow the polycrystalline silicon to dehydrogenate before becoming immersed in the molten silicon, which is desirable (col 3, ln 1-15).

Holder et al does not teach intermittent feeding.

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In a method of manufacturing silicon single crystals, Kamio et al teaches continuously or intermittently feeding a silicon starting material so as to maintain constant the liquid level of the molten material (col 1, ln 5-67), this reads on applicant's intermittent delivery comprising on and off periods.

It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Holder by using the feeding apparatus taught Kamio for feeding the silicon intermittently to control a desired flow of silicon material.

Also, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Holder by using an intermittent flow because there are only two types of flow, intermittent or continuous, as evidenced by Kamio et al and the selection of one known equivalent technique for another may be obvious even if the prior art does not expressly suggestion the substitution, *Ex parte Novak* 16 USPQ 2d 2041 (BPAI 1989).

Referring to claim 4-5, the combination of Nagai et al and Holder teach the interface between the unmelted polycrystalline silicon and the upper surface of the molten silicon is approximately equidistant from the center of the unmelted polycrystalline and equidistant from the interior wall of the crucible ('993 Fig 3).

Referring to claim 1, the combination of Holder and Kamio et al teach a feed tube 42 in a crucible, note Figure 2 of Holder et al.

Referring to claims 6-8, the combination of Holder and Kamio et al teach 55 kg of chunk polycrystalline for a 100 kg total charge ('993 col 5, ln 5-15); therefore the percentage of chunk polycrystalline can be determined to be 55% (55/100), which reads on applicant's range of 50-60%.

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Referring to claim 9-10, the combination of Holder and Kamio et al teaches the molten silicon comprises about 25-50% of the total surface area ('993 col 4, ln 45-65 and Figs 2-4), this reads on applicant's d ranges about 65%-85% of D.

Referring to claim 11-12, the combination of Holder and Kamio et al teach rotating the crucible ('429 col 6, ln 45-60).

Referring to claim 13-14, the combination of Holder and Kamio et al does not teach rotating at about 2.1 rpm. The rate of crucible rotation is dependant on the flow rate of the feed pipe. It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Holder and Kamio et al by optimizing the rotation speed of the crucible to obtain same by conducting routine experimentation of a result effective variable (MPEP 2144.05). Also, rotating a crucible at 2 rpm is well known in the art, note Nagai et al (US 5,868,835) below. Furthermore, the selection of reaction parameters such as temperature and concentration is obvious (In re Aller 105 USPQ 233, 255 (CCPA 1955)).

Referring to claim 15-18, the combination of Holder and Kamio et al teaches a feed rate of 5-15 kg/hr ('993 claim 14).

Referring to claim 19-31, the combination of Holder and Kamio et al is silent to the value of the f , t_{on} and t_{off} parameters. The combination of Holder and Kamio et al teaches intermittent feeding ('429 col 1) and the feeding of the silicon is such that a constant level is maintained ('429 col 1). Therefore, the amount of time for commencing and stopping the flow and the flow rate of silicon are result effective variable, which control the thickness of the unmolten layer. It would have been obvious to a person of ordinary skill in the art at the time of the invention to

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modify the combination of Holder and Kamio et al by optimizing these parameters to obtain same by conducting routine experimentation (MPEP 2144.05).

Referring to claim 32, the combination of Holder and Kamio et al is silent to using an angle of repose valve. Angle of repose valves are conventionally used for granular materials in order to interrupt the flow of granular material. Angle of repose valves are well known in the art, as evidenced by Crawley (US 5,642,751) and Boone et al (US 5,205,998), below.

Referring to claim 33-34, the combination of Holder and Kamio et al teaches a vertical type feed tube so that it is not directly above the center of the exposed unmelted silicon ('993 Figs 2-4).

Referring to claim 35, the combination of Holder and Kamio et al teaches a feed is sprayed ('993 Fig 2-3), this reads on applicant's spray type feed tube.

Referring to claim 36-52, the combination of Holder and Kamio et al is silent to portion of the exposed unmelted polycrystalline silicon upon which the granular polycrystalline silicon is delivered is a wedge that extends radially outward from about the center to the interface between the unmelted silicon and the upper surface of the molten silicon. However, the combination of Holder and Kamio et al teach rotating at a similar rate and flowing granular silicon intermittently, as applicant, therefore this is inherent to the combination of Holder and Kamio et al. The combination of Holder and Kamio et al also does not teach the wedge angle. The wedge angle is merely the size of the wedge. Changes in size and shape are held to be obvious (MPEP 2144.03).

Referring to claim 53-58, the combination of Holder and Kamio et al is silent to the position of wedges. However, the combination of Holder and Kamio et al teach rotating at a

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similar rate and flowing granular silicon intermittently, as applicant, therefore this is inherent to the combination of Nagai et al and Holder.

Response to Arguments

3. Applicant's arguments filed 5/3/2006 have been fully considered but they are not persuasive.

Applicant's argument that combination of references is not motivated because the processes described in each reference are fundamentally unrelated (pg 3-6) is noted but is not found persuasive. Applicant alleges that Holder's process relates to feeding granular polysilicon to form a melt and Kamio teaches an unrelated process of feeding polysilicon intermittently or continuously for maintaining a melt level during growth. The process are related because Holder and Kamio relate to a Czochralski method of crystal growth wherein polysilicon is used form a melt. Although Kamio teaches a process where a melt is maintained at a constant level, the process are still related as method of supplying polysilicon to a crucible. A person of ordinary skill in the art would have found it obvious to modify Holder's method of supplying silicon continuous with the known process of intermittently feeding silicon, as taught by Kamio.

Applicant's argument that Kamio et al teaches away from intermittently feeding is noted but is not found persuasive. Applicant alleges that Kamio teaches continuously flowing polysilicon in multiple sections of the disclosure; therefore teaches away from intermittent flow. Disclosed examples and preferred embodiments do not constitute a teaching away from a broader disclosure or non-preferred embodiment (MPEP 2123). Kamio teaches intermittent flow is a known method of supplying silicon. Kamio merely teaches preferred embodiment using

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continuous flow, which does not constitute a teaching away from the broader disclosure of intermittent flow.

Applicant's argument that intermittent feeding and continuous feeding are not equivalent is noted but is not found persuasive. Applicant alleges that intermittent and continuous feeding are not equivalents because intermittent feeding has an improved effect of increasing yield (pg 9-10). Although, applicant alleges that superior effects result when using intermittent feeding rather than continuous feeding, the process still produce similar effects. Intermittent and continuous feeding are both capable of supplying silicon at the same rate; therefore have the same effect. As method of supplying silicon at a desired rate, continuous and intermittent feeding are equivalents.

Applicant's argument that the prior art does not teaches intermittently supplying unmelted silicon is noted but is not found persuasive. Applicant alleges that Kamio teaches intermittently supplying molten material (pg 11-13). Kamio merely teaches an example of known method of intermittent feeding, where molten material is feed to the a crucible (col 1, ln 55 to col 2, ln 11). Kamio broadly teaches intermittently supplying silicon starting material and is not limited to molten material (col 1, ln 55-65). Therefore, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Holder's granular feeding of unmelted silicon with Kamio's teaching of intermittently feeding a silicon starting material.

Applicant's argument that flow rate, on and off periods are not result effective variable for amount of silicon material supplied is noted but is not found persuasive. Applicant alleges that these variables are not disclosed by the prior art; therefore a person of ordinary skill in the art would not optimize these parameters. Although Kamio does not specifically state those

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parameters are result effect variable, a person of ordinary skill in the art would have known that the desired amount of silicon supplied is dependant of the flow rate and the period of intermittent supplying; therefore it would have been obvious to a person of ordinary skill in the art at the time of the invention to optimize those parameters by conducting routine experimentation.

Applicant's argument that the size of the wedge is unobvious is noted but is not found persuasive. Applicant alleges that intermittently feeding silicon will not produce a wedge. Holder teaches supplying silicon, which forms a pile with a peak (Fig 3). Intermittently supplying the silicon, as taught by Kamio, is expected to produce a wedge because the silicon wedge is taught by applicant to form by intermittently supplying silicon. There are no additional steps taught by applicant to produce a wedge other than intermittently supplying silicon; therefore intermittently supplying silicon on the unmelted silicon taught by Holder is expected to produce a wedge. The size of the wedge can be changed by changing the duration of silicon flow.

In response to applicant's argument that the references fail to show certain features of applicant's invention, it is noted that the features upon which applicant relies (i.e., simultaneous pulling and replenishing (pg 19)) are not recited in the rejected claim(s). Although the claims are interpreted in light of the specification, limitations from the specification are not read into the claims. See *In re Van Geuns*, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993). There is no claimed pulling step in claim 68.

Conclusion

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

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Ogure et al (US 5,820,649) teaches pelletized silicon material falls intermittently into a silicon melt (col 2, ln 55-65).

Barclay et al (US 5,569,325) teaches the addition of feed material over time can be carried out intermittently in which portion of the feed material are introduced at discreet intervals of time or continuously in which the feed material is being constantly metered.

Nagai et al (US 5,868,835) teaches rotating a crucible at 2 rpm while feeding silicon to silicon melt (col 5, ln 55-67).

Crawley (US 5,642,751) teaches angle of repose valves have typically been used for granular materials in order to interrupt the flow of granular material (col 1, ln 10-15).

Boone et al (US 5,205,998) teaches an angle of repose valve to block the flow for high purity silicon (col 1, ln 50-55 and col 2, ln 1-67).

Holder (US 5,919,303) teaches loading a crucible with chunk polysilicon and granular polysilicon (Abstract).

Fuerhoff (US 6,454,851) teaches a wedge and feeding granular polysilicon and feeding is controlled in response to the relative position to the sidewall of the crucible (Abstract).

5. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire **THREE MONTHS** from the mailing date of this action. In the event a first reply is filed within **TWO MONTHS** of the mailing date of this final action and the advisory action is not mailed until after the end of the **THREE-MONTH** shortened statutory period, then the shortened statutory period


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will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew J. Song whose telephone number is 571-272-1468. The examiner can normally be reached on M-F 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Yogendra Gupta can be reached on 571-272-1316. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.


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July 7, 2006